Thyristor Semiconductor Device - Page 1 of 1



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Inclos	ure Material:
Plastic	
Overal	I Length:
Betwee	en 4.32 millimeters and 5.33 millimeters
Termir	nal Length:
12.7 m	illimeters
Overal	l Width:
Betwee	en 3.18 millimeters and 4.18 millimeters
Functi	on For Which Designed:
Rectifie	er
Interna	al Configuration:
Junctio	on contact
Joint E	Electronic Device Engineering Council/jedec/case Outline Designation:
To-92	
Electro	ode Internally-electrically Connected To Case:
Collect	or
Mount	ing Method:
Termin	al
Semic	onductor Material:
Silicon	
Voltag	e Rating In Volts Per Characteristic:
100.0	repetitive peak reverse voltage
Curren	nt Rating Per Characteristic:
0.80 ar	nperes source cutoff current preset
Power	Rating Per Characteristic:
0.1 wat	tts small-signal input power, common-collector blank
Maxim	um Operating Tempurature Per Measurement Point:
125.0 c	degrees celsius junction
Specia	Il Features:
Junctio	n pattern arrangement: pnpn
Termir	nal Type And Quantity:
3 unins	sulated wire lead
Shelf L	.ife:
N/a	
Unit O	f Measure:
Demili	tarization:
No	
Fiig:	
A110a	